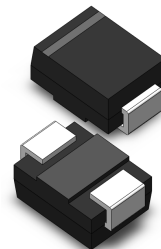


**VOLTAGE RANGE: 600 V**

**CURRENT: 2.0 A**

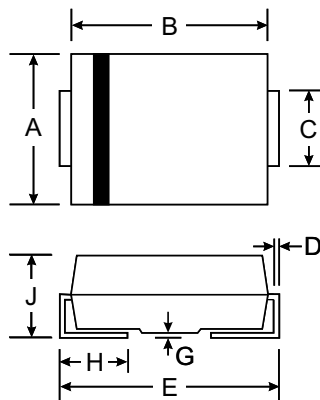
### Features

- Glass passivated chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power losses
- High forward surge capability



### Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)



SMB(DO-214AA)		
Dim	Min	Max
A	3.30	3.94
B	4.06	4.70
C	1.91	2.21
D	0.15	0.31
E	5.00	5.59
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameters	Symbol	USB260	Unit
Device marking code		U60	
Maximum repetitive peak reverse voltage	$V_{RRM}$	600	V
Maximum RMS voltage	$V_{RMS}$	420	V
Maximum DC blocking voltage	$V_{DC}$	600	V
Maximum average forward rectified current (see Fig. 1)	$I_{F(AV)}$	2.0	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	90	A
Non-repetitive avalanche energy at $I_{AS} = 2.0\text{ A}$ , $L = 10\text{ mH}$ , $T_J = 25^\circ\text{C}$	$E_{AS}$	20	mJ
Operating junction and storage temperature range	$T_J, T_{STG}$	- 55 to + 150	$^\circ\text{C}$

Parameters	Test condition	Symbol	Typ.	Max.	Unit
Breakdown voltage	at $I_R = 10\ \mu\text{A}$ $T_J = 25^\circ\text{C}$	$V_{(BR)}$	600 (minimum)		V
Instantaneous forward voltage <sup>(1)</sup>	at $I_F = 1\text{ A}$ $T_J = 25^\circ\text{C}$	$V_F$	1.25	-	V
	at $I_F = 2.0\text{ A}$ $T_J = 25^\circ\text{C}$		1.5	1.6	
	$T_J = 125^\circ\text{C}$		1.0	1.1	
Maximum reverse current <sup>(1)</sup>	at $V_R = 600\text{ V}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$I_R$	- 30	5.0 100	$\mu\text{A}$
Maximum reverse recovery time	$I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{rr} = 0.25\text{ A}$	$t_{rr}$	30		ns
Typical junction capacitance	at 4.0 V, 1 MHz	$C_J$	45		pF

Notes: (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

Parameters	Symbol	USB260	Unit
Typical thermal resistance <sup>(1)</sup>	$R_{\theta JA}$	45	$^\circ\text{C/W}$
	$R_{\theta JL}$	10	

Notes: (1) Units mounted on P.C.B. with 2.0 x 2.0" copper pad areas

### Ratings and Characteristics Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

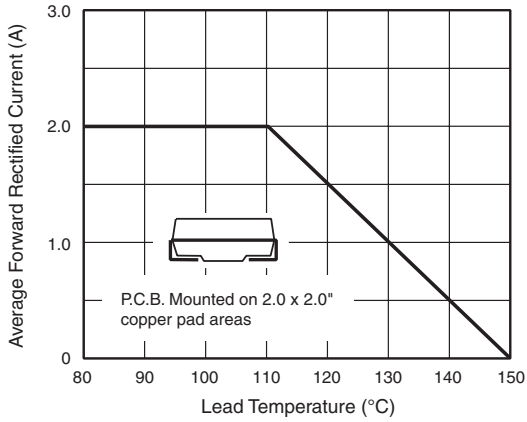


Figure 1. Maximum Forward Current Derating Curve

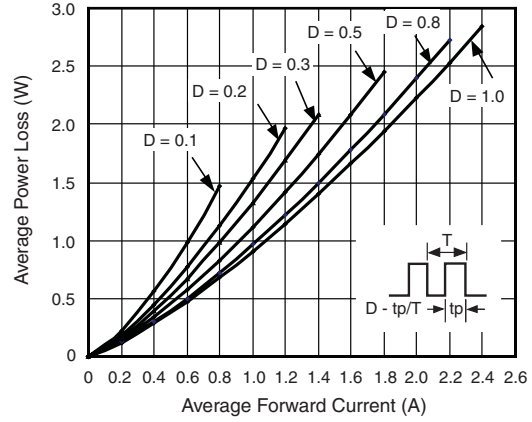


Figure 2. Forward Power Loss Characteristics

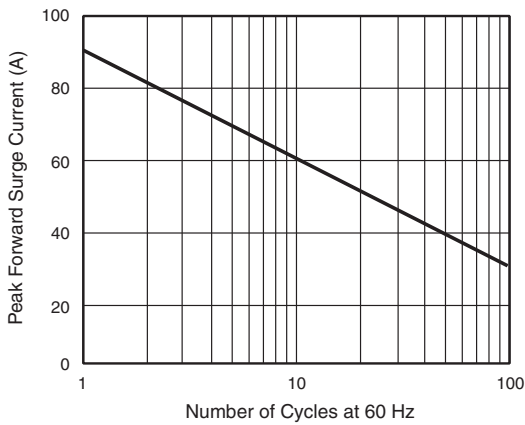


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

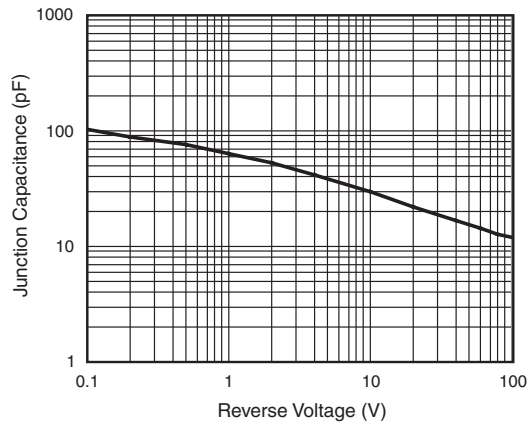


Figure 6. Typical Junction Capacitance

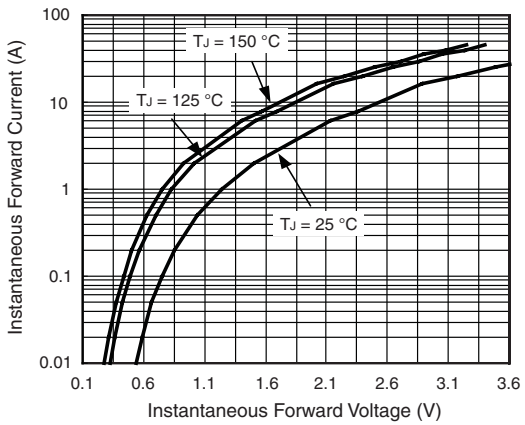


Figure 4. Typical Instantaneous Forward Characteristics

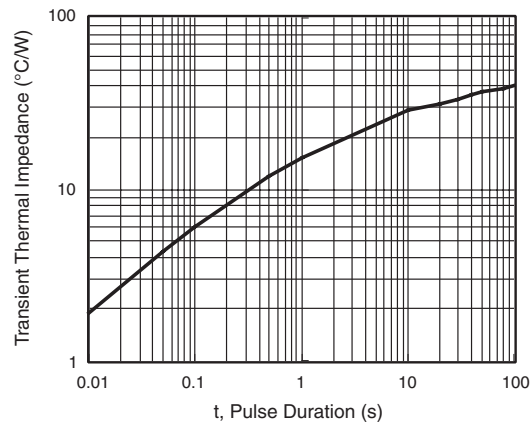


Figure 7. Typical Transient Thermal Impedance